Docket No. 99-005

Express Mail: EM 083176878 US

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Patent No.:

6,998,625

Issue Date:

February 14, 2006

Title:

Ion Implanter Having Two-Stage Deceleration Beamline

Assignee: Inventors:

Varian Semiconductor Equipment Associates, Inc. Charles M. McKenna et al.

Art Unit:

2881

WRITTEN CONSENT OF THE ASSIGNEE UNDER 37 C.F.R. § 1.324(b)(3)

Dear Sir:

As the Assignee of the above-referenced U.S. Patent No. 6,998,625, Varian Semiconductor Equipment Associates, Inc., hereby consents to the addition of MANNY SIERADZKI as an inventor of the same. I, David H. Hwang, Esq., General Counsel (Acting) and Chief IP Counsel, am authorized by Varian Semiconductor Equipment Associates, Inc. to sign on behalf of the Assignee. Also enclosed herewith is a proper statement under 37 CFR §3.73(b) establishing that Varian Semiconductor Equipment Associates, Inc. is the Assignee of the entire right, title, and interest in U.S. Patent 6,998,625.

Respectfully submitted,

Date:

David H. Hwang, Esq.

General Counsel (Acting)

Chief IP Counsel

Varian Semiconductor Equipment Associates, Inc.

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